

Abstracts

High Gain Monolithic W-Band Low-Noise Amplifiers Based on Pseudomorphic High Electron Mobility Transistors (Correction)

D.-W. Tu, S.W. Duncan, A. Eskandarian, B. Golja, B.C. Kane, S.P. Svensson, S. Weinreb and N.E. Byer. "High Gain Monolithic W-Band Low-Noise Amplifiers Based on Pseudomorphic High Electron Mobility Transistors (Correction)." 1995 Transactions on Microwave Theory and Techniques 43.6 (Jun. 1995 [T-MTT]): 1404-1404.

In the above paper, Fig. 3. was printed upside down.

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